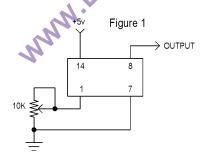
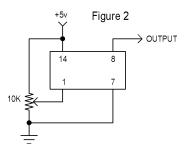
MXO5162 Series 14 DIP, 5.0 Volt, Sinewaye, OCXO

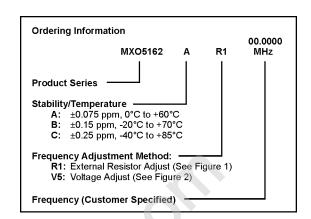


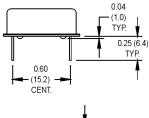


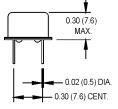
- Standard DIP/DIL package offering tight stabilities, fast warm-up, and low current
- Ideal for PCS base stations, cellular base stations, phase locking, and SAR/SAT applications
- 5V Operation

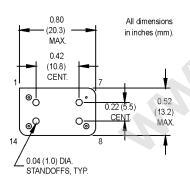












Pin Connections

PIN	FUNCTION
1	Frequency Adjust
7	Case ground & supply return
8	R.F. Output
14	Supply (+)

	PARAMETER	Symbol	Min.	Max.	Units	Condition	
Electrical Specifications	Frequency Range	F	10	20	MHz		
	Operating Temperature	TA	(See Ordering Information)		ပွ		
	Stability Over Temperature	∆F/F	(See Ordering Information)		ppm		
	Short Term Stability			5 x 10 ⁻¹¹		0.1 to 30 secs.	
	Aging (First Year)			±0.7	ppm		
	Aging (10 Years)			±4.0	ppm		
	Frequency Vs. Supply			±0.1	ppm		
	Frequency Vs. Load			±0.01	ppm		
	Supply Voltage	Vcc	+4.8	+5.2	Volts		
	Warm-Up Time		To spec after 30 secs.			0°C	
	Warm-Up Current			250	mA	After 10 secs.	
	Supply Current	lcc		70	mA	+30°C	
				110	mA	-20°C	
	Output Signal		Sinewave				
	Output Level		1	2	V pk-pk		
	Harmonics		-10		dBc		
	Spurious Modes		-70		dBc		
	Output Load			1K ∏5 pF		+10%	
	Frequency Adjustment (Pin 1)		±4		ppm	See Figure 1 or 2	
	Tuning Slope			Positive			
	Input Impedance (Pin 1)		4.7K		ohms	. (3)	
	Phase Noise					(BW = 1 Hz)	
	1 Hz			-80	dBc/Hz	Offset from carrier	
	10 Hz			-110	dBc/Hz	XVX	
	100 Hz			-135	dBc/Hz	0,0	
	1 kHz			-145	dBc/Hz	01	
	10 kHz			-150	dBc/Hz		
Environmental	Mechanical Shock 2000 g		g, 0.3 mS, 1/2 sine				
	Vibration	2000 Hz, 10 g					
	Storage Temperature	-55°C to +125°C			7.0	,	
<u>vi</u>	Hermeticity	Per MIL-STD-202, Method 112			10		
μ̈	Solderability EIAJ-STD-002						
	7.						

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